

HI2301

8-Bit, 30 MSPS, Video A/D Converter with Amplifier/Clamp

January 1998

NOT RECOMMENDED FOR NEW DESIGNS
 See HI2302
 contact our Technical Support Center at
 1-888-INTERSIL or www.intersil.com/tsc

Features

- Resolution 8-Bit ± 0.5 LSB (DNL)
- Maximum Sampling Frequency 30 MSPS
- Low Power Consumption, 120mW (Including Reference Current)
- Standby Function
- Amplifier Functions
 - Built-In 3x Amplifier (15MHz Band)
 - 2-Input Selector Function Provided
- Built-In Input Clamp Function (DC Restore)
- Clamp ON/OFF Function
- Internal Voltage Reference
- Three-State TTL Compatible Output
- Power Supply +5V Single or +4.75/3.3V Dual
- Direct Replacement for Sony CXD2301

Applications

- Desktop Video
- Multimedia
- Video Digitizing
- Image Scanners

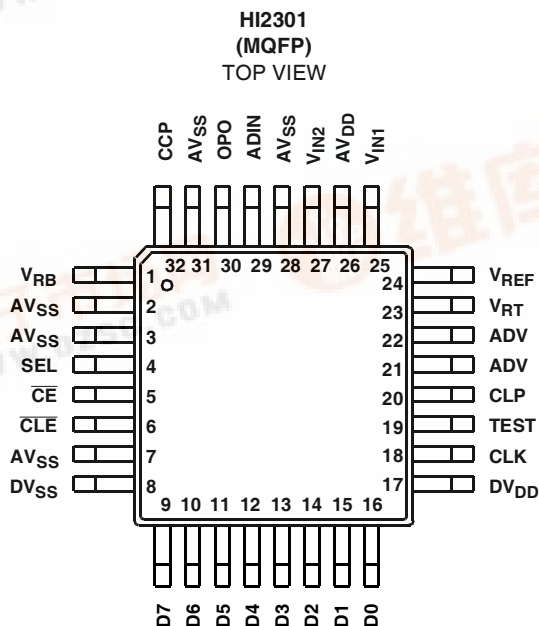
Description

The HI2301 is an 8-bit CMOS analog-to-digital converter for video use that features a sync clamp function and on-chip amplifier. The adoption of a 2-step parallel method realizes low power consumption and a maximum conversion speed of 30 MSPS.

Ordering Information

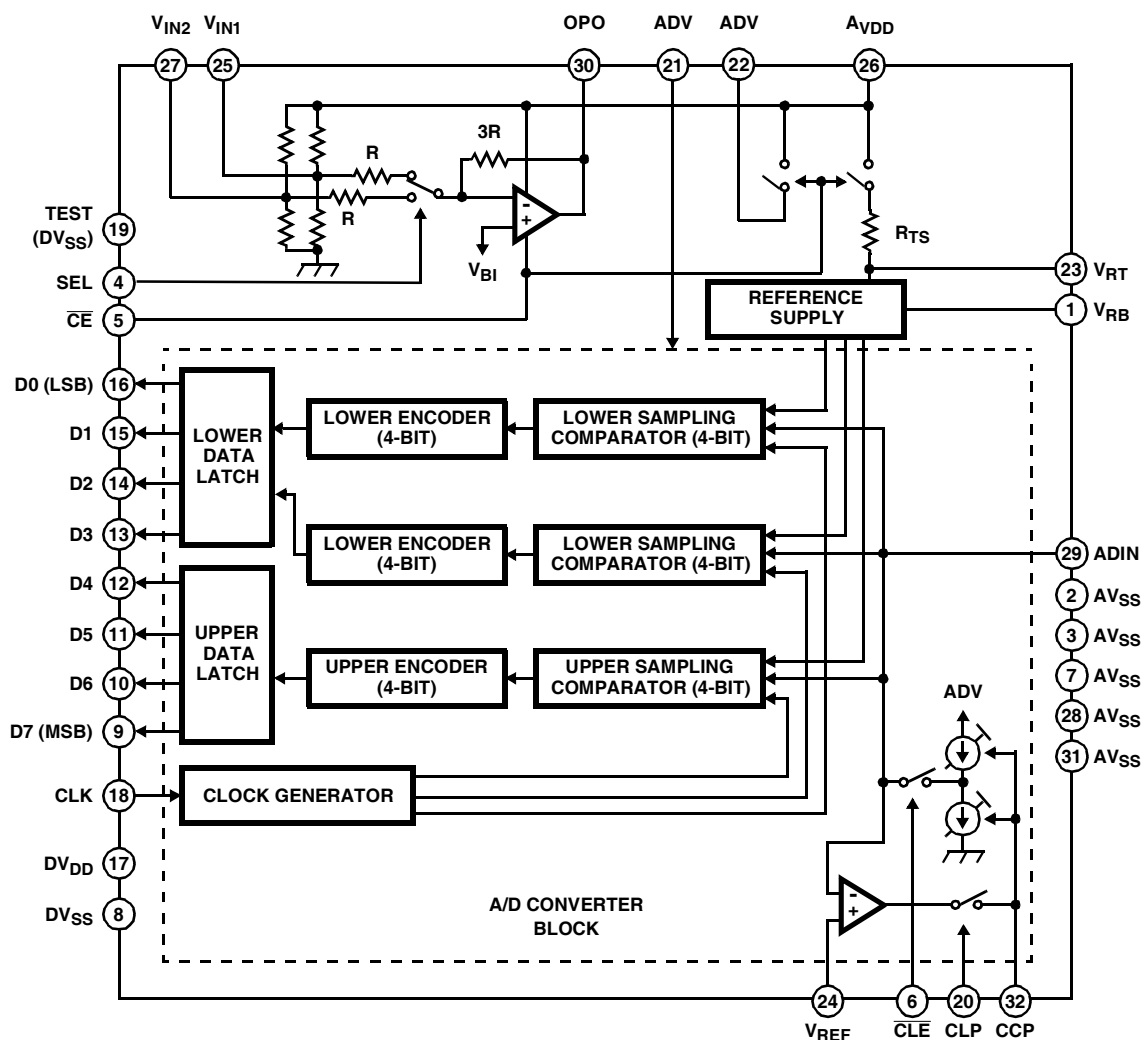
PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
HI2301JCQ	-20 to 75	32 Ld MQFP	Q32.7x7-S

Pinout



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Functional Block Diagram



Pin Descriptions

PIN NO.	SYMBOL	EQUIVALENT CIRCUIT	DESCRIPTION
1	V_{RB}		Reference voltage (bottom) connect to AV_{SS} for normal use. When another external voltage is input, connect an external $0.1\mu F$ capacitor and retain a 1.5V differential compared to the top reference voltage.
23	V_{RT}		Reference voltage (top) by setting V_{RB} to AV_{SS} , outputs approximately 1.5V. Connect only a $0.1\mu F$ external by-pass capacitor for normal use. When another external voltage is input, it must be 2.2V or lower.
2, 3, 7, 28, 31	AV_{SS}		Analog GND.

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Pin Descriptions (Continued)

PIN NO.	SYMBOL	EQUIVALENT CIRCUIT	DESCRIPTION
4	SEL		Switches the input of the 3x amplifier. When SEL is at Low level, V_{IN1} is selected. When SEL is at High level, V_{IN2} is selected.
5	\overline{CE}		Standby function ON/OFF selector. In standby state when High.
19	TEST		Fix to V_{SS} for normal use.
6	\overline{CLE}		When \overline{CLE} = Low: Clamp function is enabled. When \overline{CLE} = High: Clamp function is disabled, and only the normal A/D converter function is enabled.
18	CLK		Clock Input.
20	CLP		Inputs the clamp pulse to Pin 20 (CLP). Clamps the High interval signal voltage.
8	DVSS		Digital GND.
9 to 16	D ₇ to D ₀		D ₇ (MSB) to D ₀ (LSB) output. Outputs Low level in standby. In operation, the phase of D ₇ to D ₀ output is inverted against the phase of ADIN.
17	DVDD		5V or 3.3V
21	ADV		Short Pins 21 and 22, and connect 0.1 μ F external capacitor.
22	ADV		
24	V _{REF}		Clamp reference voltage input. Clamps so that the reference voltage and the clamp interval ADIN input signal are equal. The reference voltage is more than 0.5V.

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Absolute Maximum Ratings $T_A = 25^\circ\text{C}$

Supply Voltage (V_{DD})	7V
Reference Voltage (V_{RT}, V_{RB})	$V_{DD} 0.5$ to $V_{SS} -0.5V$
Input Voltage, Analog (V_{IN})	$V_{DD} 0.5$ to $V_{SS} -0.5V$
Input Voltage, Digital (V_{IH}, V_{IL})	$V_{DD} 0.5$ to $V_{SS} -0.5V$
Output Voltage, Digital (V_{OH}, V_{OL})	$V_{DD} 0.5$ to $V_{SS} -0.5V$

Operating Conditions

Supply Voltage ($IDV_{SS} - AV_{SS}$)	0 to 100mV
Single Power Supply (AV_{DD}, DV_{DD})	$5.0 \pm 0.25V$
Dual Power Supply (AV_{DD})	$4.75 \pm 0.25V$
(DV_{DD})	$3.3 \pm 0.3V$
Reference Input Voltage (V_{RB})	0V to 2.2V
(V_{RT})	0V to 2.2V
Analog Input (ADIN)	More than 1.2V _{P-P}
Clock Pulse width, t_{PW1}	16ns (Min)
t_{PW0}	16ns (Min)
Temperature Range (T_{OPR})	-20 to 75°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

- θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (°C/W)
MQFP Package	122
Maximum Junction Temperature (Plastic Package)	150°C
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(Lead Tips Only)	

Electrical Specifications

Electrical Specifications; When using a single power supply ($f_C = 30$ MSPS, $AV_{DD} = DV_{DD} = +5V$, $V_{RB} = 0V$, $V_{RT} = 1.5V$, $T_A = 25^\circ\text{C}$)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS	
Supply Current	$I_{AD} + I_{DD}$	$f_C = 35$ MSPS, NTSC Ramp Wave Input	-	27	35	mA	
Standby Supply Current	I_{STB}	$\overline{CE} = DV_{DD}$	-	130	200	μA	
Max Conversion Rate	f_C Max	$V_{IN} = 0V$ to 1.5V, $f_{IN} = 1\text{kHz}$ Ramp	30	-	-	MSPS	
Min Conversion Rate	f_C Min		-	-	0.5	MSPS	
ADIN Input Band (At -1dB)	BW		-	20	-	MHz	
ADIN Input Capacitance	C_{ADIN}	$V_{IN} = 0.75V + 0.07V_{RMS}$	-	8	-	pF	
Reference Resistance (V_{RT} to V_{RB})	R_{REF}		230	330	440	Ω	
Self Bias	V_{RT}	$V_{RB} = AV_{SS}$	1.38	1.52	1.66	V	
Offset Voltage	EOT		-40	-20	0	mV	
	EOB		+25	+45	+65	mV	
Digital Input Voltage	V_{IH}		3.5	-	-	V	
	V_{IL}		-	-	0.5	V	
Digital Input Current	I_{IH}	$DV_{DD} = \text{Max}$	$V_{IH} = V_{DD}$	-	-	5	μA
	I_{IL}		$V_{IL} = 0V$	-	-	5	μA
Digital Output Current	I_{OH}	$DV_{DD} = \text{Min}$	$V_{OH} = V_{DD} - 0.5V$	-1.1	-2.5	-	mA
	I_{OL}		$V_{OL} = 0.4V$	3.7	6.5	-	mA
Output Data Delay	t_{DL}	With TTL 1 Gate and 10pF Load	7	13	25	ns	
Integral Nonlinearity Error	E_L	$f_C = 30$ MSPS, $V_{IN} = 0V$ To 1.5V	-	+0.5	+1.3	LSB	
Differential Gain Error	DG	NTSC 40 IRE Mod Ramp, $f_C = 14.3$ MSPS	-	1	-	%	
Differential Phase Error	DP		-	0.5	-	Degrees	
Aperture Jitter	t_{AJ}		-	30	-	ps	
Sampling Delay	t_{SD}		-	2	-	ns	
Clamp Offset Voltage	EOC	$V_{ADIN} = \text{DC}$ $PWS = 3\mu$	$V_{REF} = 0.5V$	0	+20	+40	mV
			$V_{REF} = 1.5V$	-40	-20	0	mV

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Electrical Specifications Electrical Specifications; When using a single power supply ($f_C = 30$ MSPS, $AV_{DD} = DV_{DD} = +5V$, $V_{RB} = 0V$, $V_{RT} = 1.5V$, $T_A = 25^\circ C$) (Continued)

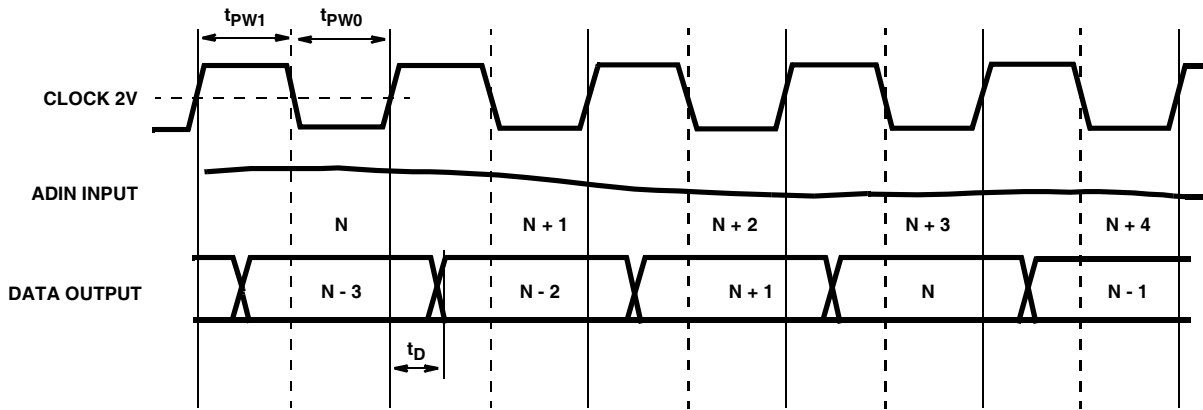
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Clamp Pulse Delay	t_{CPD}		-	25	-	ns
Amplifier Gain		DC To 15MHz	8.5	9.5	10.5	dB
V_{IN1} and V_{IN2} Bias Voltage	$V_{BI1,2}$	When Open	-	1.9	-	V
V_{IN1} and V_{IN2} Input Resistance	$R_{I1,2}$		19	27	35	k Ω
V_{IN1} and V_{IN2} Input Capacitance	$C_{I1,2}$		-	15	-	pF

Electrical Specifications When Using a Dual Power Supply ($f_C = 30$ MSPS, $AV_{DD} = DV_{DD} = +5V$, $V_{RT} = 1.5V$, $V_{RB} = 1.5V$, $T_A = 25^\circ C$)

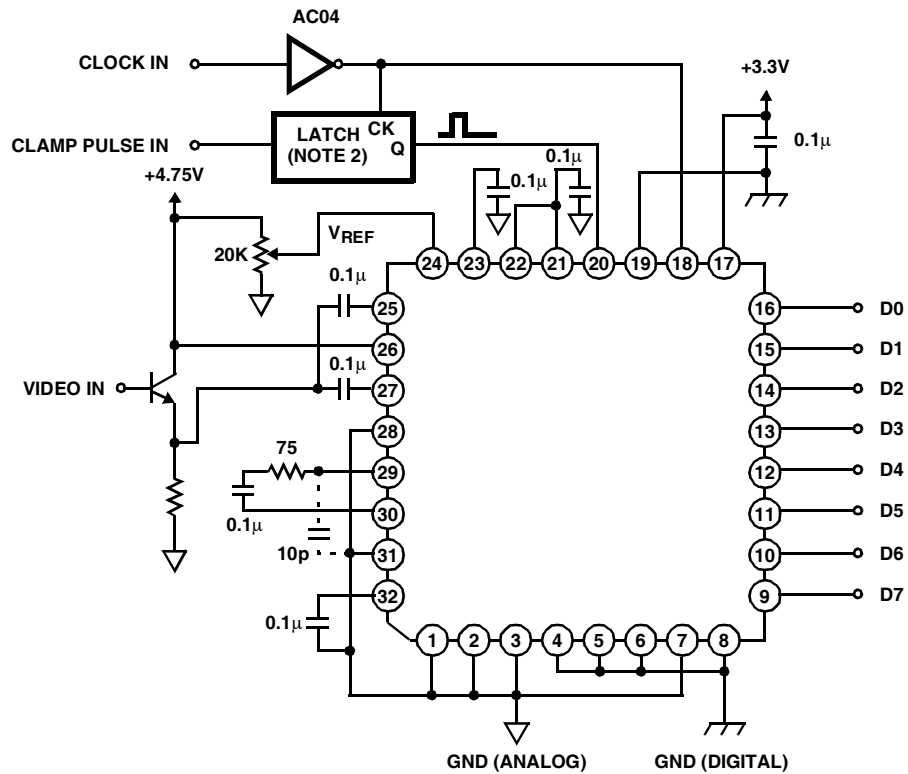
(2) When Using A Dual Power Supply $f_C = 30$ MSPS, $AV_{DD} = 4.75V$, $DV_{DD} = 0V$, $V_{RT} = 1.5V$, $T_A = 25^\circ C$							
Analog Supply Current	I_{AD}	$f_C = 30$ MSPS, NTSC Ramp Wave Input		-	24	32	mA
Digital Supply Current	I_{DD}	$f_C = 30$ MSPS, NTSC Ramp Wave Input		-	1	2	mA
Standby Supply Current	I_{STB}	$\overline{CE} = DV_{DD}$		-	130	200	μA
Maximum Conversion Rate	f_C Max	$V_{IN} = 0$ to $1.5V$ $f_{IN} = 1kHz$ Ramp		30	-	-	MSPS
Minimum Conversion Rate	f_C Min			-	-	0.5	MSPS
ADIN Input Band (at -1dB)	BW			-	20	-	MHz
ADIN Input Capacitance	C_{ADIN}	$V_{IN} = 0.75V + 0.07V_{RMS}$		-	8	-	pF
Referenced Resistance (V_{RT} to V_{RB})	R_{REF}			230	330	440	Ω
Self Bias	V_{RT}	$V_{RB} = AV_{SS}$		1.44	1.52	1.6	V
Offset Voltage	E_{OT}			-40	-20	0	mV
	E_{OB}			+25	+45	+65	mV
Digital Input Voltage	V_{IH}			2.5	-	-	V
	V_{IL}			-	-	0.5	V
Digital Input Current	I_{IH}	$DV_{DD} = Max$	$V_{IH} = DV_{DD}$	-	-	5	μA
	I_{IL}		$V_{IL} = 0V$	-	-	5	μA
Digital Output Current	I_{OH}	$DV_{DD} = Min$	$V_{OH} = V_{DD} - 0.5V$	-1.1	-2.5	-	mA
	I_{OL}		$V_{OL} = 0.4V$	3.7	6.5	-	mA
Output Data Delay	t_{DL}	With TTL 1 Gate and 10pF Load		7	13	25	ns
Integral Nonlinearity Error	E_L	$f_C = 30$ MSPS, $V_{IN} = 0$ to $1.5V$		-	+0.5	+1.3	LSB
Differential Nonlinearity Error	E_D	$f_C = 30$ MSPS, $V_{IN} = 0$ to $1.5V$		-	± 0.3	± 0.5	LSB
Differential Gain Error	DG	NTSC 40 IRE Mod Ramp, $f_C = 14.3$ MSPS		-	1	-	%
Differential Phase Error	DP			-	0.5	-	deg
Aperture Jitter	t_{AJ}			-	30	-	ps
Sampling delay	t_{SD}			-	2	-	ns
Clamp Offset Voltage	E_{OC}	$V_{IN} = DC$ $PWS = 3\mu s$	$V_{REF} = 0.5V$	0	+20	+40	mV
			$V_{REF} = 1.5V$	-40	-20	0	mV
Clamp Pulse Delay	t_{CPD}			-	25	-	ns
3x Amplifier Gain		DC to 15MHz		8.5	9.5	10.5	dB
V_{IN1} and V_{IN2} Bias Voltage	$V_{BI1,2}$	When Open		-	1.8	-	V
V_{IN1} and V_{IN2} Input Resistance	$R_{I1,2}$			19	27	35	k Ω
V_{IN1} and V_{IN2} Input Capacitance	$C_{I1,2}$			-	15	-	pF

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Timing Chart



Application Circuits



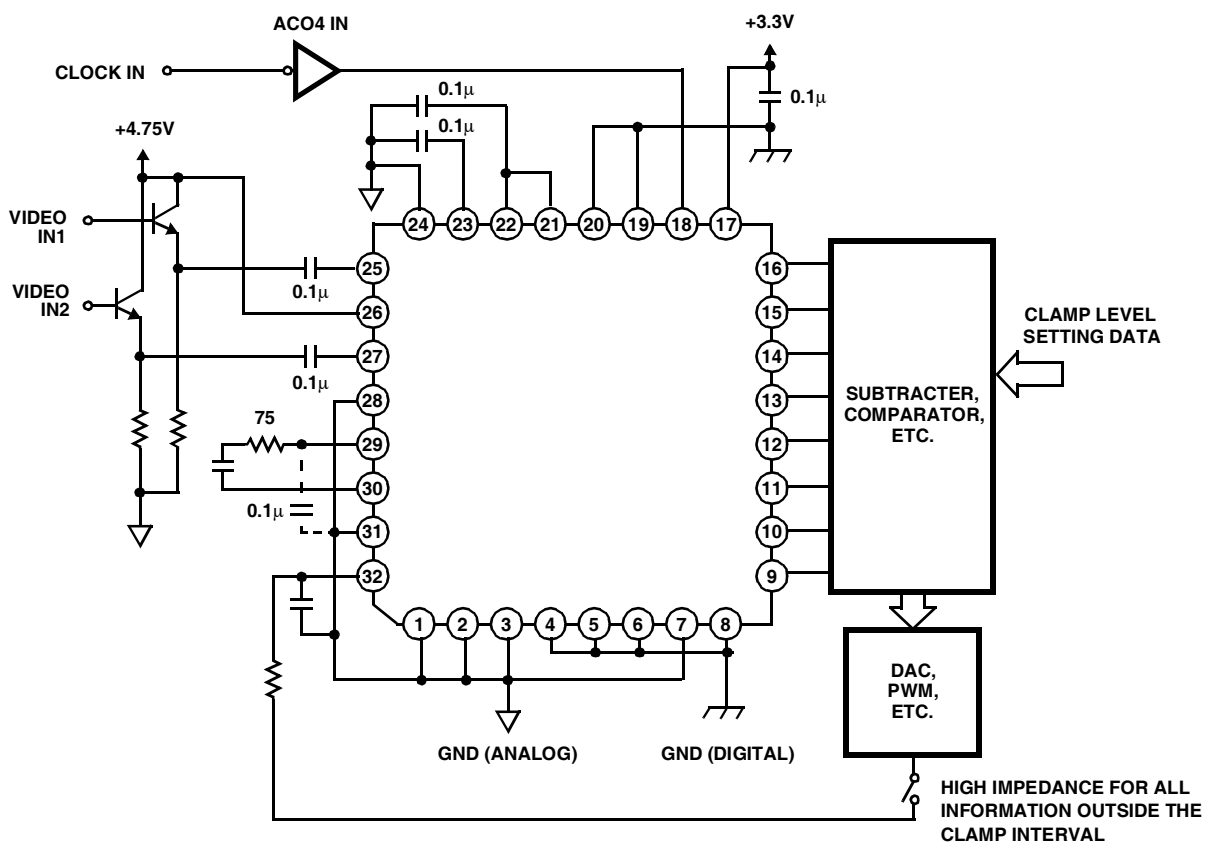
NOTE:

- Although the ADC sampling clock latches the clamp pulse, it is not needed for basic clamp operation. However, depending on the relationship between the sampling frequency and the clamp pulse frequency, a small beat might be generated as V_{SAG} . The latch circuit is valid at this time.

FIGURE 1. CLAMP USAGE EXAMPLE (USING SELF BIAS, CIRCUIT WHEN USING THE INTERNAL AMPLIFIER)

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Application Circuits (Continued)



NOTES:

3. The relationship between the CCP voltage (Pin 32) variation and the ADIN voltage variation is position phase.
4. $\Delta ADIN / \Delta V_{CCP} = 3.0$ ($f_s = 30$ MSPS).

FIGURE 2. DIGITAL CLAMP USAGE EXAMPLE (USING SELF BIAS), CIRCUIT WHEN USING THE INTERNAL AMPLIFIER

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Application Circuits (Continued)

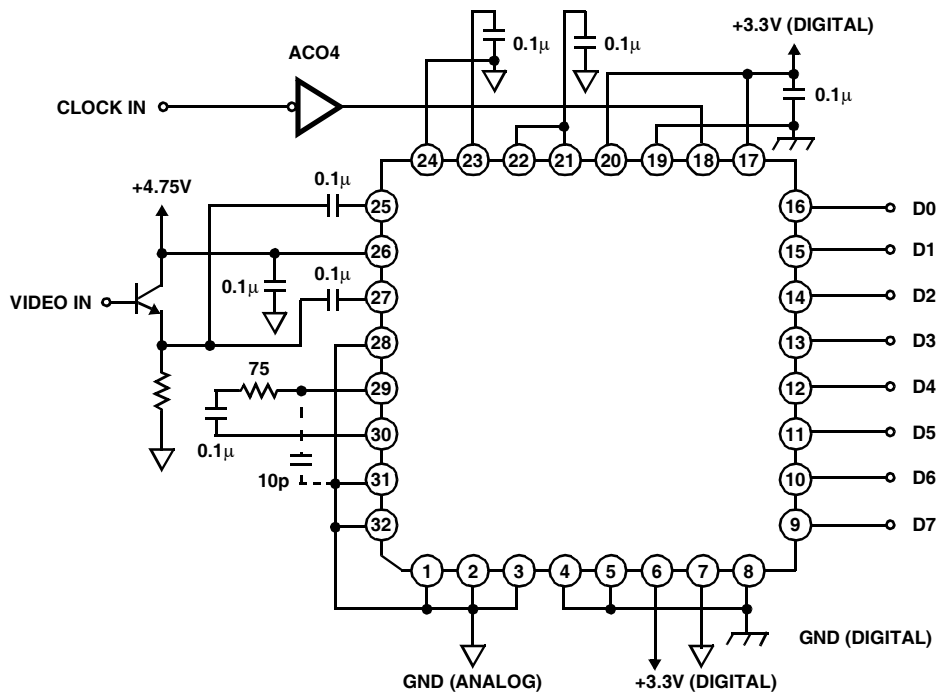
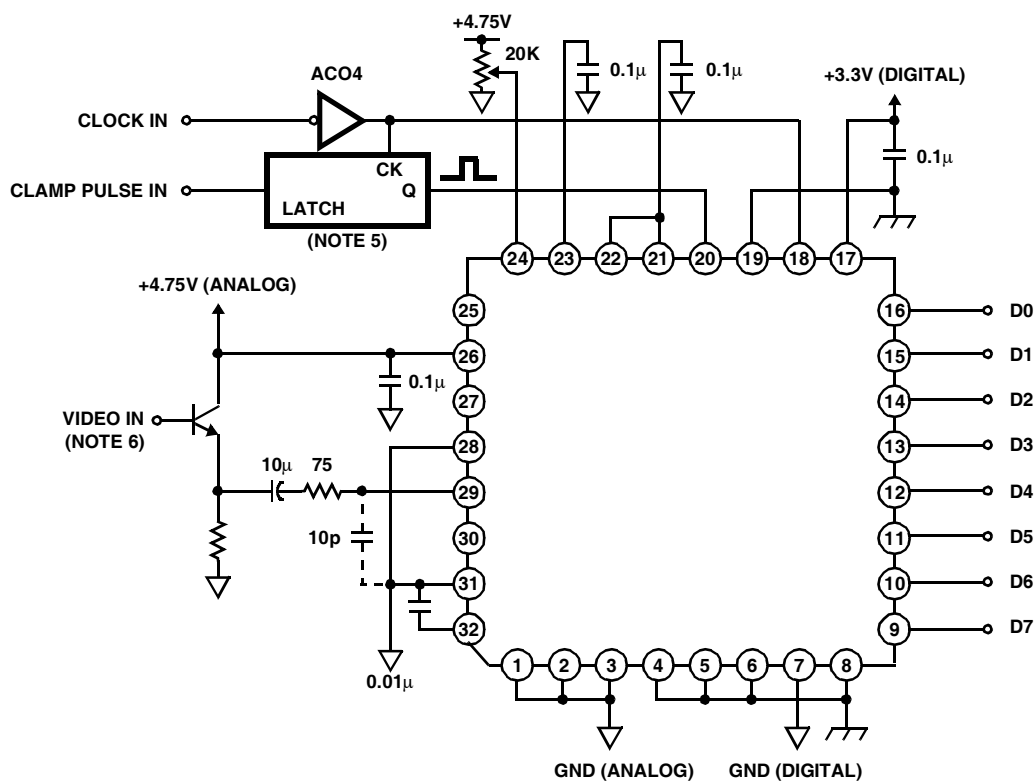


FIGURE 3. WHEN NOT USING THE CLAMP, CIRCUIT WHEN USING THE INTERNAL AMPLIFIER

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Application Circuits (Continued)



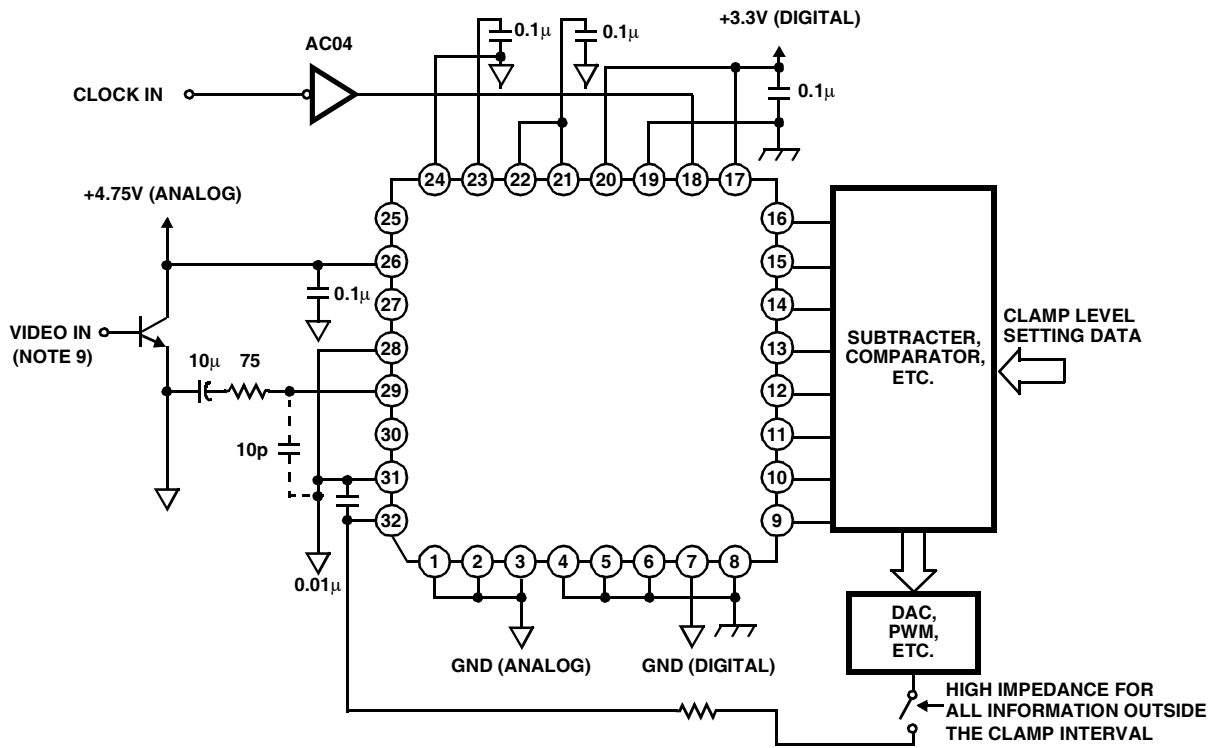
NOTES:

5. Although the ADC sampling clock latches the clamp pulse, it is not needed for basic clamp operation. However, depending on the relationship between the sampling frequency and the clamp pulse frequency, a small aberrant might be generated as V_{SAG} . The latch circuit is valid at this time.
6. Take care that the phase of ADIN input is inverted against the phase of the digital output, because the use of the built-in inverting amplifier is standard. (Refer to "Digital Output".)

FIGURE 4. CLAMP USAGE EXAMPLE WHEN NOT USING THE INTERNAL AMPLIFIER

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Application Circuits (Continued)

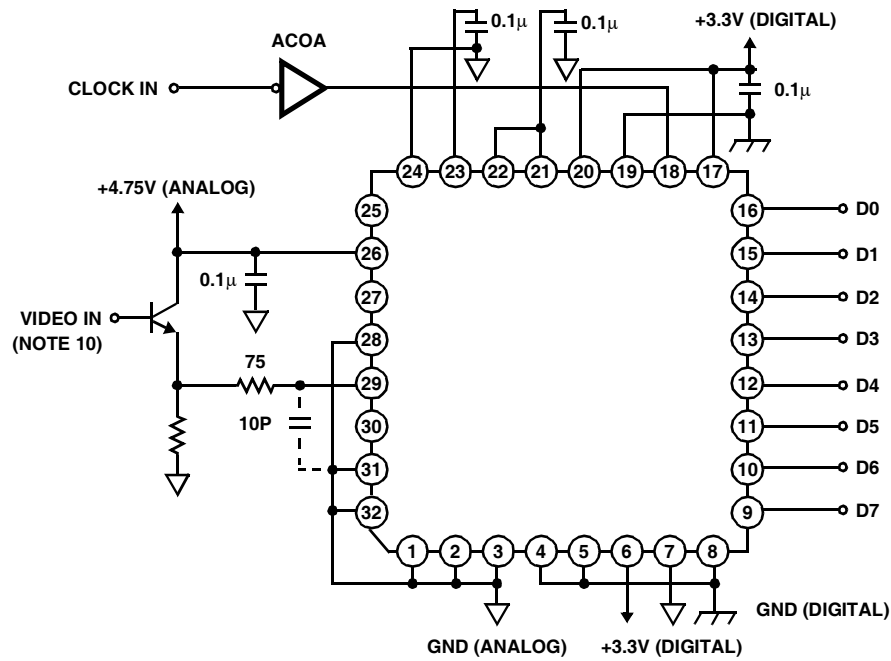


NOTES:

7. The relationship between the CCP voltage (Pin 32) variation and the ADIN voltage variation is positive phase.
8. $\Delta V_{ADIN}/\Delta V_{CCP} = 3.0$ ($f_s = 20$ MSPS).
9. Take care that the phase of ADIN input is inverted against the phase of the digital output, because the use of the built-in inverting amplifier is standard. (Refer to "Digital Output.")

FIGURE 5. DIGITAL CLAMP USAGE EXAMPLE

Application Circuits (Continued)



NOTE:

- Take care that the phase of ADIN input is inverted against the phase of the digital output, because the use of the built-in inverting amplifier is standard. (Refer to "Digital Output".)

FIGURE 6. WHEN NOT USING THE CLAMP

Typical Performance Curves

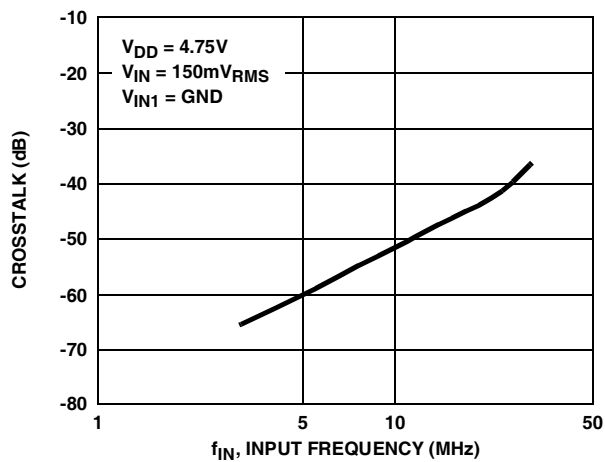


FIGURE 7. INPUT FREQUENCY OF V_{IN2} vs CROSSTALK $V_{IN2} \rightarrow V_{IN1}$

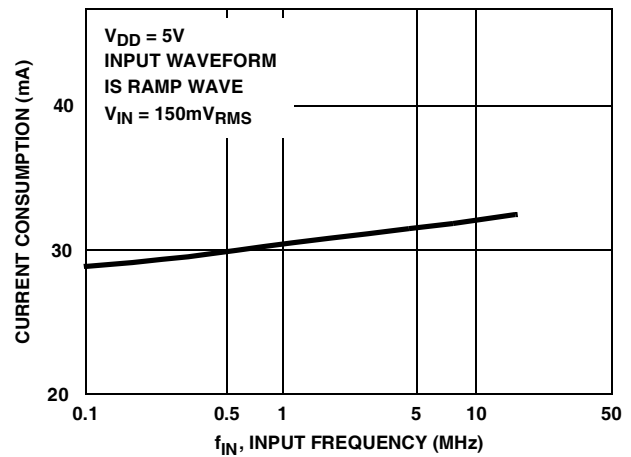


FIGURE 8. INPUT FREQUENCY vs CURRENT CONSUMPTION

Typical Performance Curves

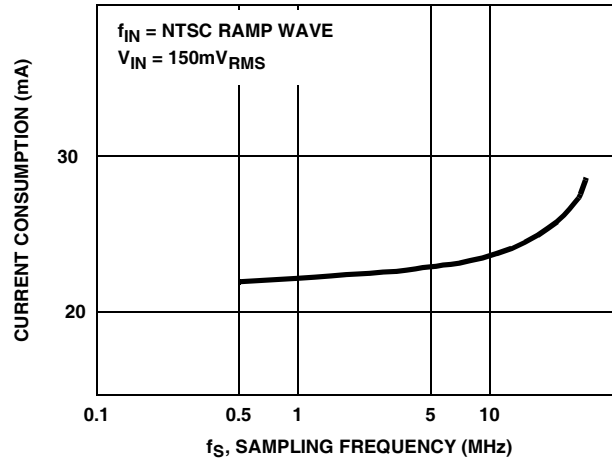


FIGURE 9. SAMPLING FREQUENCY vs CURRENT CONSUMPTION